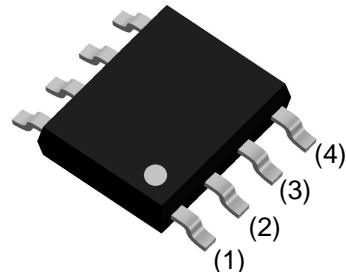


## WPMD4953

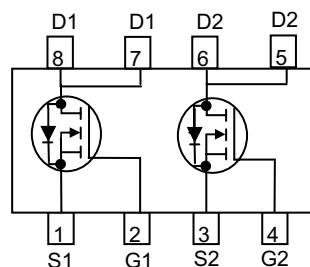
Dual P-Channel, -30V, -4.9A, Power MOSFET

[Http://www.willsemi.com](http://www.willsemi.com)

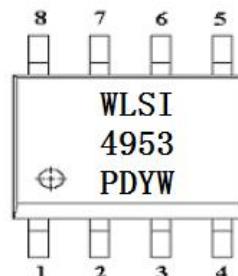
<b>V<sub>DS</sub> (V)</b>	<b>R<sub>DS(on)</sub> (Ω)</b>
<b>-30</b>	0.049@ V <sub>GS</sub> =-10V
	0.070@ V <sub>GS</sub> =-4.5V



**SOP-8L**



**Pin configuration (Top view)**



WLSI = Company  
 4953 = Device Code  
 PD = Special Code  
 Y = Year  
 W = Week(A~z)

### Marking

## Features

- Super high density cell design for extremely low R<sub>DS(ON)</sub>
- Exceptional on-resistance and maximum DC current capability
- SOP-8L package design

## Applications

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

## Order information

<b>Device</b>	<b>Package</b>	<b>Shipping</b>
WPMD4953-8/TR	SOP-8L	4000/Reel&Tape

## Absolute Maximum ratings

Parameter	Symbol	10 S	Steady State	Unit
Drain-Source Voltage	V <sub>DS</sub>	-30	V	
Gate-Source Voltage	V <sub>GS</sub>	±20		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	I <sub>D</sub>	-4.9	A
	T <sub>A</sub> =70°C		-3.9	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	P <sub>D</sub>	1.9	W
	T <sub>A</sub> =70°C		1.2	
Continuous Drain Current <sup>b</sup>	T <sub>A</sub> =25°C	I <sub>D</sub>	-4.5	A
	T <sub>A</sub> =70°C		-3.6	
Maximum Power Dissipation <sup>b</sup>	T <sub>A</sub> =25°C	P <sub>D</sub>	1.6	W
	T <sub>A</sub> =70°C		1.0	
Pulsed Drain Current <sup>c</sup>	I <sub>DM</sub>	-25		A
Operating Junction Temperature	T <sub>J</sub>	150		°C
Lead Temperature	T <sub>L</sub>	260		°C
Storage Temperature Range	T <sub>stg</sub>	-55 to 150		°C

## Thermal resistance ratings

Single Operation					
Parameter	Symbol	Typical	Maximum	Unit	
Junction-to-Ambient Thermal Resistance <sup>a</sup>	t ≤ 10 s	R <sub>θJA</sub>	56	65	°C/W
	Steady State		87	105	
Junction-to-Ambient Thermal Resistance <sup>b</sup>	t ≤ 10 s	R <sub>θJA</sub>	64	76	°C/W
	Steady State		96	115	
Junction-to-Case Thermal Resistance	Steady State	R <sub>θJC</sub>	32	40	
Dual Operation					
Junction-to-Ambient Thermal Resistance <sup>a</sup>	t ≤ 10 s	R <sub>θJA</sub>	61	70	°C/W
	Steady State		92	112	
Junction-to-Ambient Thermal Resistance <sup>b</sup>	t ≤ 10 s	R <sub>θJA</sub>	69	82	°C/W
	Steady State		102	120	
Junction-to-Case Thermal Resistance	Steady State	R <sub>θJC</sub>	36	45	

a Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper

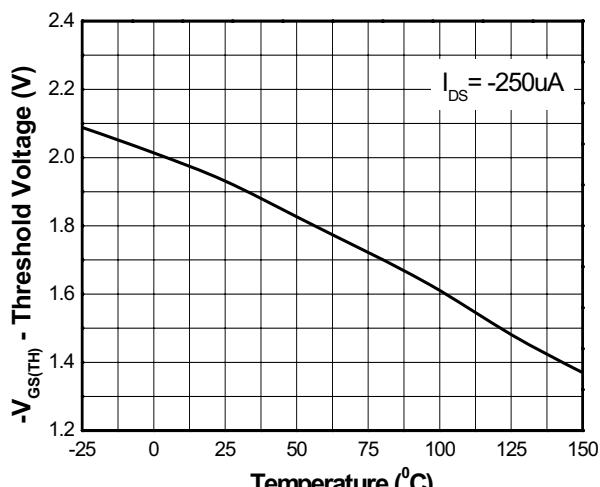
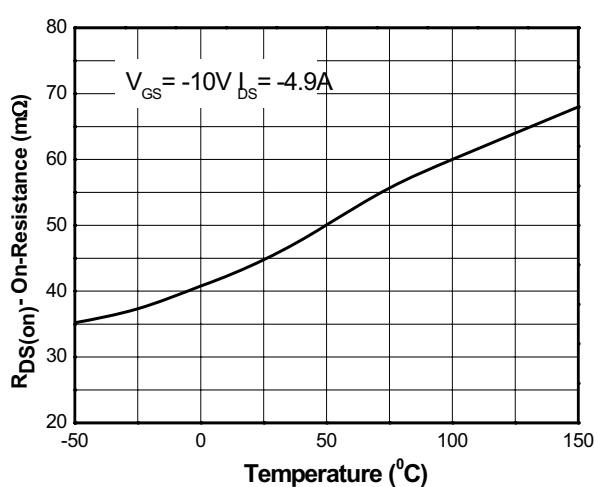
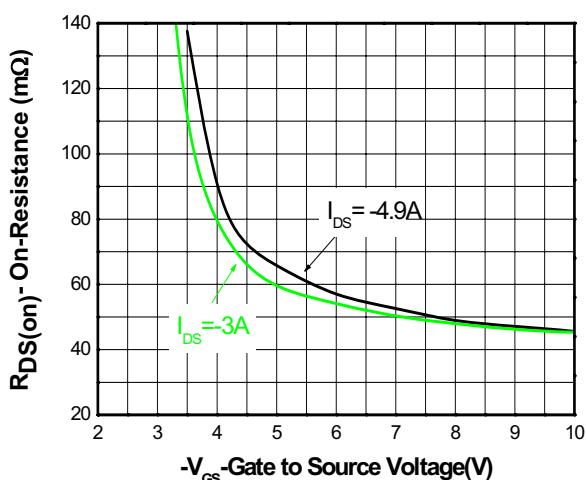
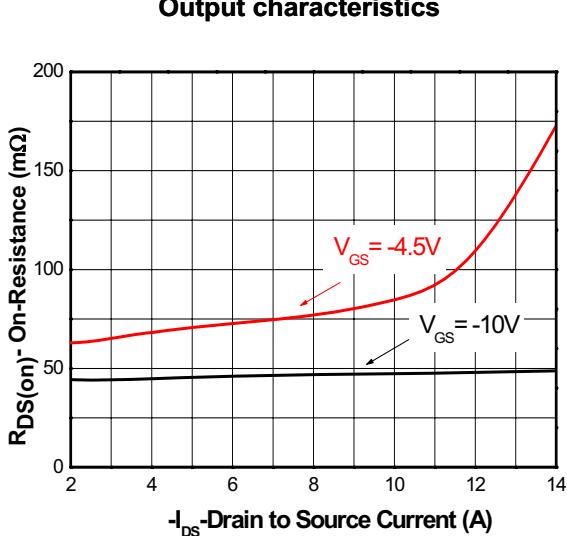
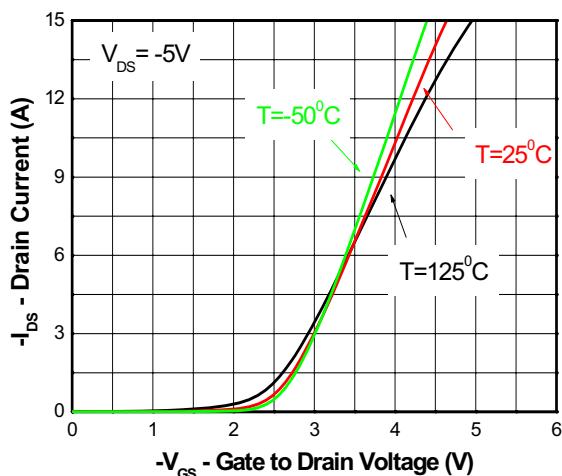
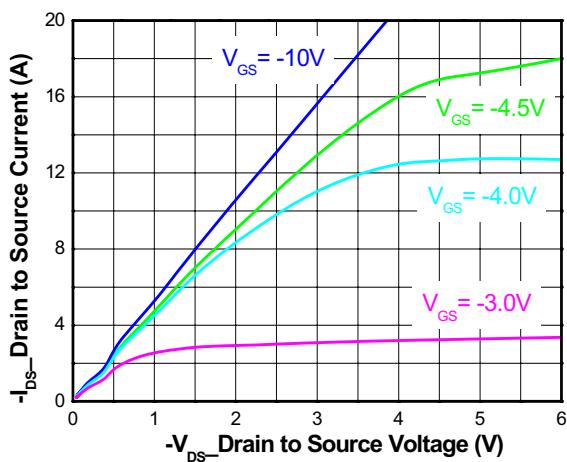
b Surface mounted on FR4 board using minimum pad size, 1oz copper

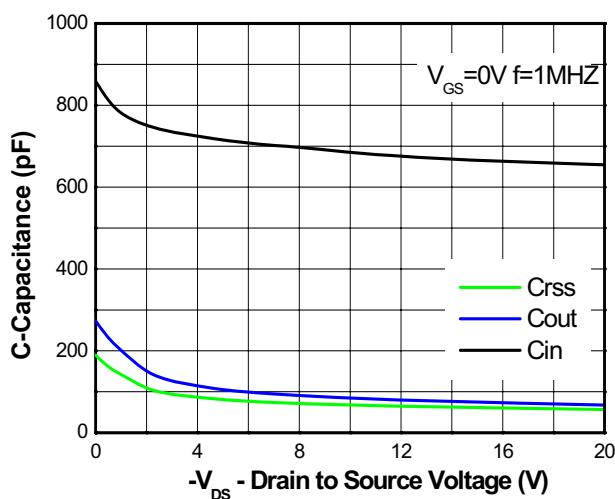
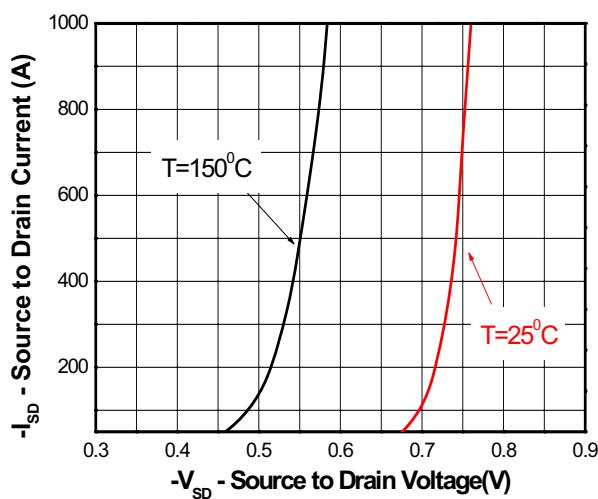
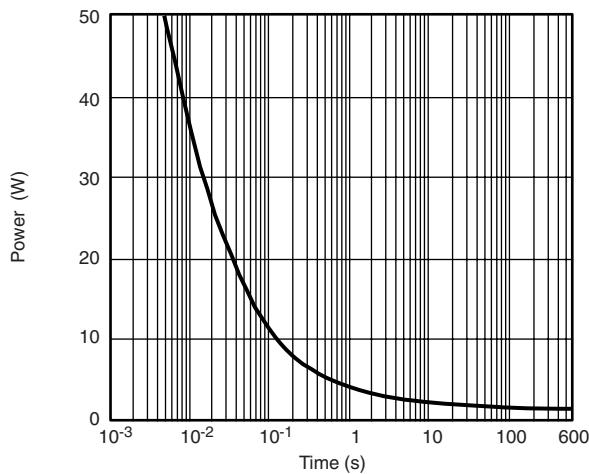
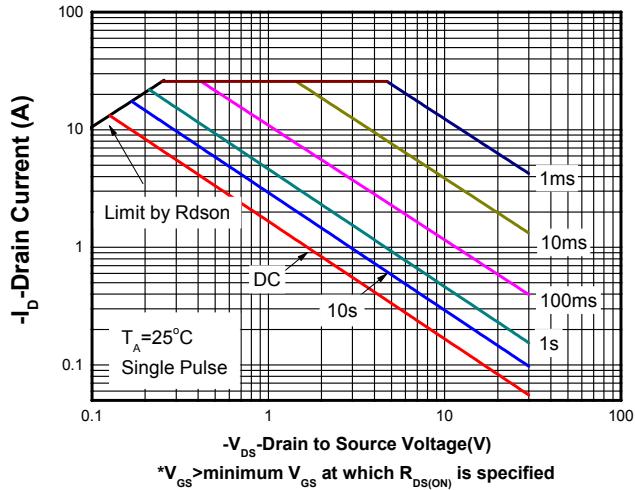
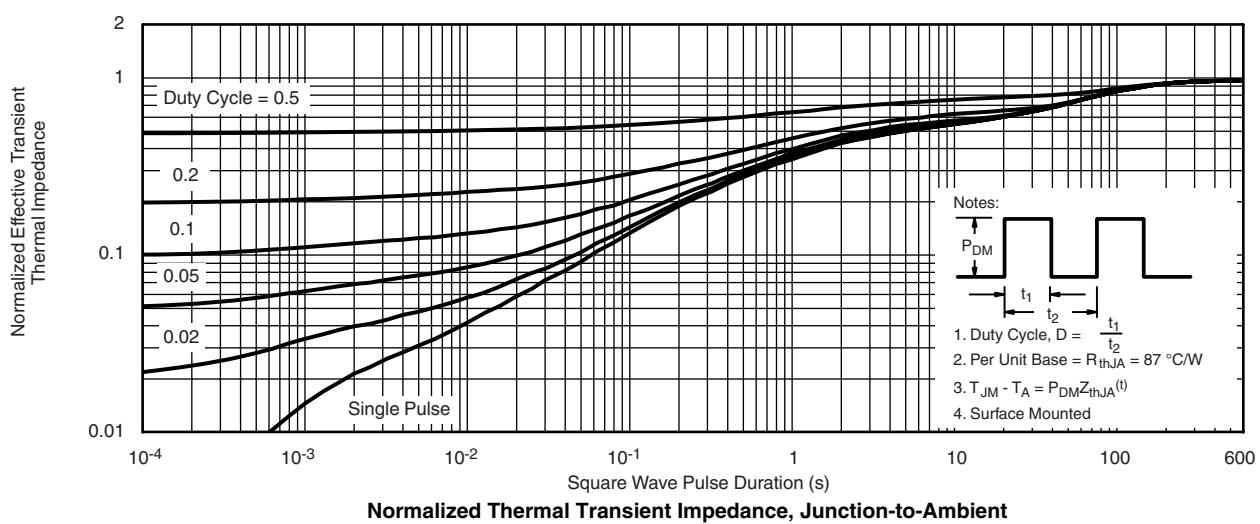
c Repetitive rating, pulse width limited by junction temperature, t<sub>p</sub>=10μs, Duty Cycle=1%

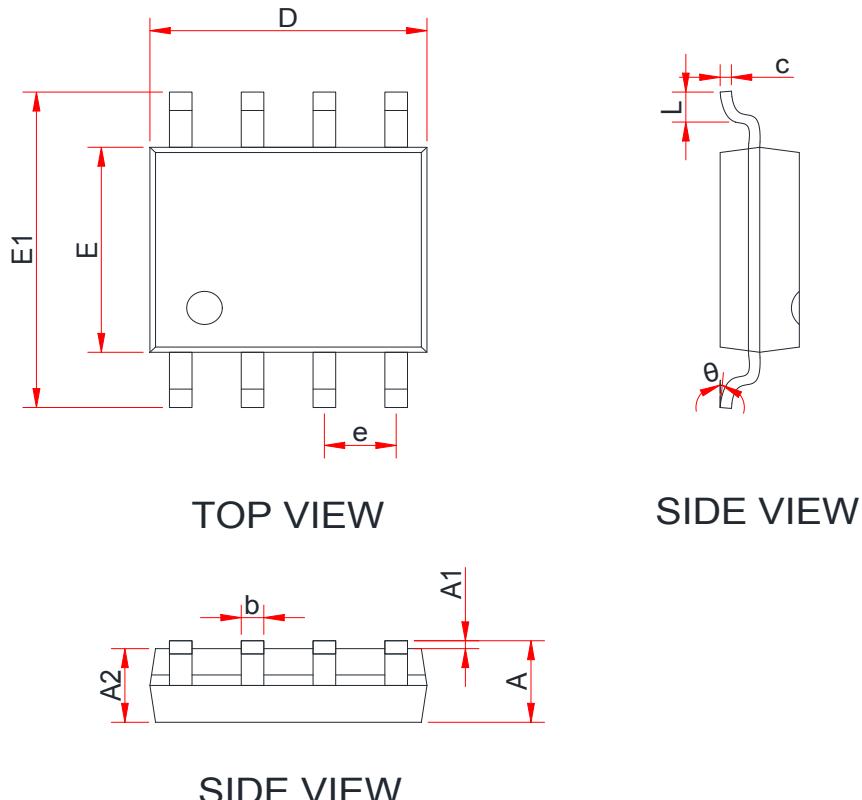
d Repetitive rating, pulse width limited by junction temperature T<sub>J</sub>=150°C.

**Electronics Characteristics (Ta=25°C, unless otherwise noted)**

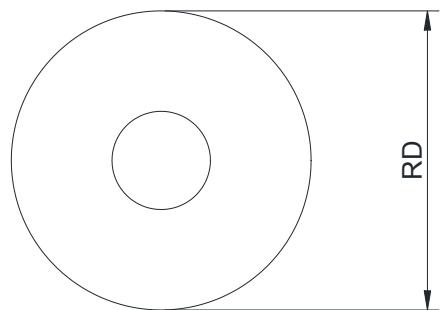
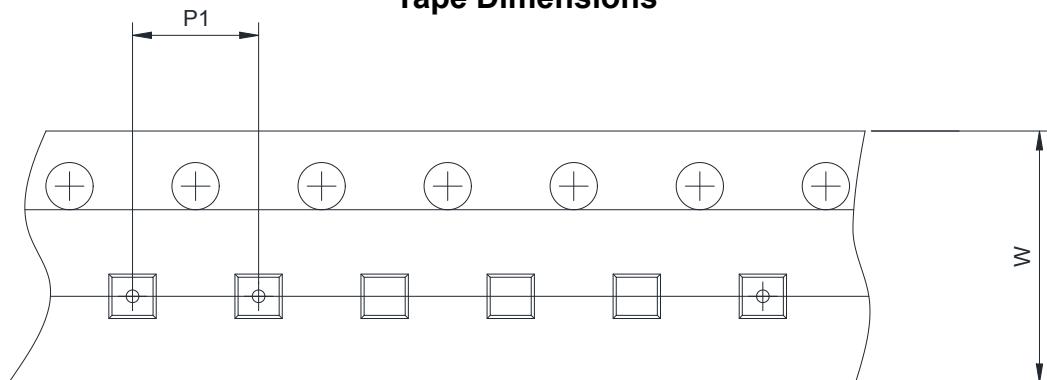
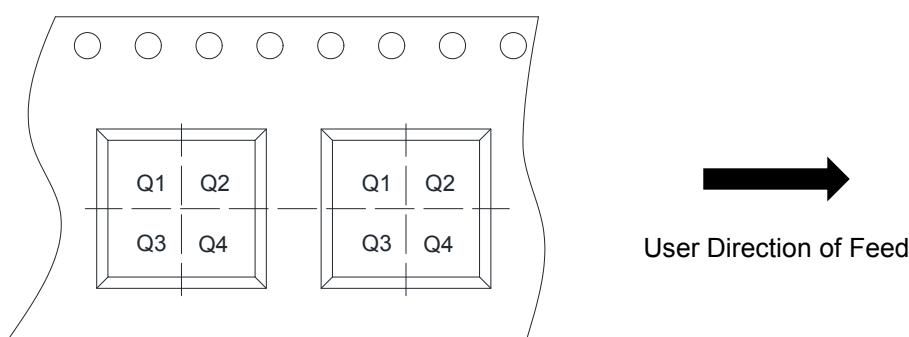
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-to-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS} = 0 \text{ V}, I_D = -250\mu\text{A}$	-30			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -24\text{V}, V_{GS} = 0\text{V}$			-1	$\mu\text{A}$
Gate-to-source Leakage Current	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20\text{V}$			$\pm 100$	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS} = V_{DS}, I_D = -250\mu\text{A}$	-1.5	-1.9	-2.5	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS} = -10\text{V}, I_D = -4.9\text{A}$		49	60	$\text{m}\Omega$
		$V_{GS} = -4.5\text{V}, I_D = -4.0\text{A}$		70	90	
Forward Transconductance	$g_{FS}$	$V_{DS} = -15 \text{ V}, I_D = -3.0\text{A}$		5.0		S
<b>CHARGES, CAPACITANCES AND GATE RESISTANCE</b>						
Input Capacitance	$C_{ISS}$	$V_{GS} = 0 \text{ V}, f = 1\text{MHz}, V_{DS} = -15 \text{ V}$		670		$\text{pF}$
Output Capacitance	$C_{OSS}$			75		
Reverse Transfer Capacitance	$C_{RSS}$			62		
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS} = -10 \text{ V}, V_{DS} = -15 \text{ V}, I_D = -4.9 \text{ A}$		14.0		$\text{nC}$
Threshold Gate Charge	$Q_{G(TH)}$			1.31		
Gate-to-Source Charge	$Q_{GS}$			1.80		
Gate-to-Drain Charge	$Q_{GD}$			1.60		
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Delay Time	$td(\text{ON})$	$V_{GS} = -10 \text{ V}, V_{DS} = -15 \text{ V}, R_L = 5.0 \Omega, R_G = 15 \Omega$		6.8		$\text{ns}$
Rise Time	$tr$			3.2		
Turn-Off Delay Time	$td(\text{OFF})$			25.2		
Fall Time	$tf$			4.4		
<b>BODY DIODE CHARACTERISTICS</b>						
Forward Voltage	$V_{SD}$	$V_{GS} = 0 \text{ V}, I_S = -1.0\text{A}$	-0.55	-0.78	-1.5	V

**Typical Characteristics (Ta=25°C, unless otherwise noted)**



**Capacitance**

**Body diode forward voltage**

**Single pulse power**

**Safe operating power**


**Package outline dimensions**
**SOP-8L**


Symbol	Dimensions In Millimeters (mm)		
	Min.	Typ.	Max.
A	1.35	1.55	1.75
A1	0.05	0.15	0.25
A2	1.25	1.40	1.65
b	0.33	-	0.51
c	0.15	-	0.26
D	4.70	4.90	5.10
E	3.70	3.90	4.10
E1	5.80	6.00	6.20
e	1.27BSC		
L	0.40	-	1.27
θ	0°	-	8°

**TAPE AND REEL INFORMATION**
**Reel Dimensions**

**Tape Dimensions**

**Quadrant Assignments For PIN1 Orientation In Tape**


RD	Reel Dimension	<input type="checkbox"/> 7inch <input checked="" type="checkbox"/> 13inch
W	Overall width of the carrier tape	<input type="checkbox"/> 8mm <input checked="" type="checkbox"/> 12mm
P1	Pitch between successive cavity centers	<input type="checkbox"/> 2mm <input type="checkbox"/> 4mm <input checked="" type="checkbox"/> 8mm
Pin1	Pin1 Quadrant	<input checked="" type="checkbox"/> Q1 <input type="checkbox"/> Q2 <input type="checkbox"/> Q3 <input type="checkbox"/> Q4

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for MOSFET category:***

***Click to view products by Will Semiconductor manufacturer:***

Other Similar products are found below :

[614233C](#) [648584F](#) [MCH3443-TL-E](#) [MCH6422-TL-E](#) [FDPF9N50NZ](#) [NTNS3A92PZT5G](#) [IRFD120](#) [IRFF430](#) [JANTX2N5237](#) [2N7000](#)  
[AOD464](#) [2SK2267\(Q\)](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [SSM6J414TU,LF\(T](#) [751625C](#)  
[IPS70R2K0CEAKMA1](#) [BSF024N03LT3 G](#) [PSMN4R2-30MLD](#) [TK31J60W5,S1VQ\(O](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#)  
[EFC2J004NUZTDG](#) [FCAB21350L1](#) [P85W28HP2F-7071](#) [DMN1053UCP4-7](#) [NTE2384](#) [NTE2969](#) [NTE6400A](#) [DMC2700UDMQ-7](#)  
[DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [SSM6P54TU,LF](#) [DMP22D4UFO-7B](#) [IPS60R3K4CEAKMA1](#)  
[DMN1006UCA6-7](#) [DMN16M9UCA6-7](#) [STF5N65M6](#) [IRF40H233XTMA1](#) [IPSA70R950CEAKMA1](#) [IPSA70R2K0CEAKMA1](#) [STU5N65M6](#)  
[C3M0021120D](#)